116TH CONGRESS 2D SESSION

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To require the Secretary of Commerce to award grants to States for the construction of microelectronics manufacturing and advanced research and development facilities, to authorize the Secretary of Defense and the Director of National Intelligence to fund the construction of microelectronics manufacturing facilities for national security needs, and to authorize additional amounts for microelectronics research and development, and for other purposes.

IN THE SENATE OF THE UNITED STATES

Mr. Cotton (for himself and Mr. Schumer) introduced the following bill; which was read twice and referred to the Committee on

A BILL

To require the Secretary of Commerce to award grants to States for the construction of microelectronics manufacturing and advanced research and development facilities, to authorize the Secretary of Defense and the Director of National Intelligence to fund the construction of microelectronics manufacturing facilities for national security needs, and to authorize additional amounts for microelectronics research and development, and for other purposes.

- 1 Be it enacted by the Senate and House of Representa-
- 2 tives of the United States of America in Congress assembled,

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	SHICTION	SHORT TITLE	

2	This Act may be cited as the "American Foundries
3	Act of 2020''.

- 4 SEC. 2. GRANTS FOR CONSTRUCTION OF MICROELEC-
- 5 TRONICS MANUFACTURING AND RESEARCH
- 6 AND DEVELOPMENT FACILITIES, AND WORK-
- 7 FORCE DEVELOPMENT.
- 8 (a) Grants for States With Demonstrated In-
- 9 TEREST IN CONSTRUCTING MICROELECTRONICS MANU-
- 10 FACTURING AND ADVANCED RESEARCH AND DEVELOP-
- 11 MENT FACILITIES.—
- 12 (1) IN GENERAL.—Not later than 180 days
- after the date of the enactment of this Act, the Sec-
- retary of Commerce, in consultation with the Sec-
- retary of Defense, shall commence carrying out a
- program on the award of grants to States described
- in paragraph (2) to assist in financing the construc-
- tion, expansion, or modernization (including acquisi-
- 19 tion of equipment and intellectual property) of
- 20 microelectronics fabrication, assembly, test, ad-
- vanced packaging, or advanced research and develop-
- 22 ment facilities.
- 23 (2) STATES DESCRIBED.—A State described in
- 24 this paragraph is a State that demonstrates to the
- 25 Secretary of Commerce the following:

1	(A) Documented interest from a microelec-
2	tronics company, that has a demonstrated abil-
3	ity to build and operate microelectronics fab-
4	rication, assembly, test, advanced packaging, or
5	advanced research and development facilities, in
6	constructing, expanding, or modernizing a com-
7	mercial microelectronics fabrication, assembly,
8	test, advanced packaging, or advanced research
9	and develop facility, or documented interest
10	from a public-private consortium that has a
11	demonstrated ability to build and operate an
12	advanced research and development facility in
13	the State.
14	(B) Documented interest from a private
15	entity to provide funding to support the con-
16	struction, expansion, or modernization of the
17	facility that is the subject of the interest docu-
18	mented under subparagraph (A).
19	(C) Commitments from such microelec-
20	tronics company or consortia to worker and
21	community investment, including—
22	(i) training and education benefits
23	paid for by the company; and

1	(ii) programs to expand employment
2	opportunity for economically disadvantaged
3	individuals.
4	(D) Commitments from regional edu-
5	cational and training entities and institutions of
6	higher education to develop curriculum or en-
7	gage in workforce training, including program-
8	ming for training and job placement of eco-
9	nomically disadvantaged individuals.
10	(E) Guaranteed State-level economic incen-
11	tives for the construction, expansion, or mod-
12	ernization of the facility described in subpara-
13	graph (B), such as site development, tax incen-
14	tives, job-training programs and State-level
15	funding for microelectronics research and devel-
16	opment.
17	(3) Limitation on grant amount.—A State
18	may not be awarded more than \$3,000,000,000
19	under paragraph (1).
20	(4) Use of funds .—
21	(A) In General.—A State receiving a
22	grant under paragraph (1) may only use the
23	amount of the grant to finance—
24	(i) the construction, expansion, or
25	modernization of a state-of-the-art micro-

1	electronics fabrication, assembly, test, ad-
2	vanced packaging, or advanced research
3	and development facility with respect to
4	which the State demonstrated to the Sec-
5	retary documented interest under para-
6	graph (2), or for similar uses in state of
7	practice and legacy facilities as deemed
8	necessary by the Secretary for national se-
9	curity and economic competitiveness;
10	(ii) to support workforce development
11	for such facility; or
12	(iii) to support site development for
13	such facility.
14	(B) Return of funds.—A State awarded
15	a grant under paragraph (1) shall return any
16	unused funds to the Treasury of the United
17	States on an agreed-upon timeframe determined
18	by the Secretary prior to issuing the funds.
19	(C) Recovery of Certain funds.—If a
20	microelectronics entity receiving grant funds
21	under this subsection engages in increased lev-
22	els of joint research and development, tech-
23	nology licensing or transfer, or investment in-
24	volving sensitive technologies with entities
25	under the foreign ownership, control, or influ-

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ence (FOCI) of the Government of the People's Republic of China or other foreign adversary during the period of the grant, as determined by the Secretary as part of a periodic review of whether a microelectronics entity participating in the program specified in this subsection is under foreign ownership, control, or influence, the Secretary shall recover the amounts provided by the Secretary under this subsection.

(5) PROHIBITION.—If pursuant to the periodic review of foreign ownership, control, or influence specified in paragraph (4)(C), the Secretary determines that a microelectronics entity is under the foreign ownership, control or influence of the Government of the People's Republic of China or other foreign adversary during the period of the grant, such entity shall be prohibited from participating in the program specified in this subsection.

(6) Nonrelocation between states.—

(A) PROHIBITION.—A State may not use any amount of a grant awarded under this subsection to induce the relocation or the movement of existing jobs from one State to another State in competition for those jobs.

1	(B) Remedies.—In the event that the
2	Secretary determines an amount of a grant
3	awarded to a State under this subsection was
4	used in violation of subparagraph (A), the Sec-
5	retary may pursue appropriate enforcement ac-
6	tions, including—
7	(i) suspension of disbursements of the
8	grant awarded; and
9	(ii) termination of the grant awarded,
10	which may include the establishment of a
11	debt requiring the recipient of the grant to
12	reimburse the amount of the grant.
13	(7) Implementation.—The Secretary shall
14	carry out this section acting through the Director of
15	the National Institute of Standards and Technology.
16	(8) Reports and notices.—
17	(A) Secretary of Commerce.—
18	(i) Report on implementation
19	PLAN.—Not later than 90 days after the
20	date of the enactment of this Act, the Sec-
21	retary shall submit to Congress a report on
22	the plans of the Secretary to carry out the
23	program required by paragraph (1).
24	(ii) Notice of Pending Award.—

1	(I) IN GENERAL.—Not later than
2	30 days before awarding a grant to a
3	State under this subsection, the Sec-
4	retary shall submit to Congress a no-
5	tice of the intended award.
6	(II) Contents.—Each notice
7	submitted under subclause (I) shall
8	include a description of the State to
9	which the Secretary intends to award
10	a grant under this subsection, the
11	project or projects for which the
12	amount of the grant is intended to be
13	used, specifics on the planned use of
14	the amounts of the grant for that
15	project, and the rationale of the Sec-
16	retary for awarding the grant.
17	(B) Comptroller general of the
18	UNITED STATES.—
19	(i) BIENNIAL REPORT.—Not later
20	than 1 year after the date on which the
21	Secretary of Commerce submits the report
22	under subparagraph $(A)(i)$ and not less
23	frequently than once every 2 years there-
24	after, the Comptroller General of the
25	United States shall submit to Congress a

1	report on the activities carried out under
2	this subsection during the previous year.
3	(ii) Contents.—Each report sub-
4	mitted under clause (i) shall include, at a
5	minimum, assessments of the following:
6	(I) How the program is being
7	carried out and how recipients of
8	grants are being selected under the
9	program.
10	(II) How other Federal programs
11	are leveraged for manufacturing, re-
12	search, and training to complement
13	the grants awarded to States under
14	this subsection.
15	(III) Outcomes of projects sup-
16	ported by grants under this sub-
17	section, including the construction, ex-
18	pansion, or modernization of a micro-
19	electronics fabrication, assembly, test,
20	advanced packaging, or advanced re-
21	search and development facilities, re-
22	search and development, workforce
23	training, employment, wages, and hir-
24	ing of economically disadvantaged
25	populations.

1	(9) Authorization of appropriations.—
2	There is authorized to be appropriated to carry out
3	this subsection \$15,000,000,000 for fiscal year
4	2021, with such amount to remain available for such
5	purpose until September 30, 2031.
6	(b) Creation, Expansion, or Modernization of
7	MICROELECTRONICS MANUFACTURING FACILITIES AND
8	Capabilities for National Security Needs.—
9	(1) Incentives authorized.—The Secretary
10	of Defense and the Director of National Intelligence,
11	in consultation with the Secretary of Commerce,
12	may jointly enter into arrangements with private
13	sector entities or consortia thereof to provide incen-
14	tives for the creation, expansion, or modernization of
15	one or more commercially competitive and sustain-
16	able microelectronics manufacturing or advanced re-
17	search and development facilities capable of pro-
18	ducing measurably secure and specialized microelec-
19	tronics for use by the Department of Defense, the
20	intelligence community, critical infrastructure sec-
21	tors of the United States economy, and other na-
22	tional security applications.
23	(2) Commercial manufacturing.—A facility
24	constructed, expanded, or modernized with an incen-
25	tive provided under paragraph (1) may—

1	(A) be principally oriented toward commer-
2	cial manufacturing; or
3	(B) devote surplus manufacturing capacity
4	to the production of commercial microelec-
5	tronics.
6	(3) Risk mitigation requirements.—A facil-
7	ity constructed, expanded, or modernized with an in-
8	centive provided under paragraph (1), or the compo-
9	nents thereof, shall—
10	(A) have the potential to perform fabrica-
11	tion, assembly, package, test, or advanced re-
12	search and development functions for classified
13	and export-controlled microelectronics;
14	(B) include management processes to iden-
15	tify and mitigate supply chain security risks;
16	and
17	(C) be able to produce microelectronics
18	consistent with applicable trusted supply chain
19	and operational security standards established
20	under section 224 of the National Defense Au-
21	thorization Act for Fiscal Year 2020 (Public
22	Law 116–92).
23	(4) National security requirements.—In
24	the provision of incentives under paragraph (1), the
25	Secretary of Defense and the Director of National

1	Intelligence shall jointly give preference to private
2	sector entities and consortia that—
3	(A) have participated in previous programs
4	and projects of the Department of Defense or
5	the Office of the Director of National Intel-
6	ligence, including—
7	(i) the Trusted Integrated Circuit pro-
8	gram of the Intelligence Advanced Re-
9	search Projects Activity;
10	(ii) trusted and assured microelec-
11	tronics projects, as administered by the
12	Department of Defense; or
13	(iii) the Electronics Resurgence Initia-
14	tive (ERI) program of the Defense Ad-
15	vanced Research Projects Agency;
16	(B) have demonstrated an ongoing com-
17	mitment to performing contracts for the De-
18	partment of Defense and the intelligence com-
19	munity;
20	(C) are approved by the Defense Counter-
21	intelligence and Security Agency or the Office
22	of the Director of National Intelligence as pre-
23	senting an acceptable security risk, taking into
24	account supply chain assurance vulnerabilities,
25	counterintelligence risks, and any risks pre-

1	sented by companies whose owners are located
2	outside the United States; and
3	(D) are evaluated periodically for foreign
4	ownership, control, or influence, consistent with
5	the determinations in paragraphs (4)(C) and
6	(5) of subsection (a).
7	(5) Use of incentives.—Incentives may be
8	provided under paragraph (1) for the construction,
9	expansion, or modernization of a facility that was
10	constructed, expanded, or modernized with funds
11	from a grant awarded under subsection (a).
12	(6) Nontraditional defense contractors
13	AND COMMERCIAL ENTITIES.—The arrangements
14	entered into under paragraph (1) shall be in the
15	form the Secretary of Defense and the Director of
16	National Intelligence determine to be appropriate to
17	encourage industry participation of nontraditional
18	defense contractors or commercial entities and may
19	include a contract, a grant, a cooperative agreement,
20	a commercial agreement, the use of other trans-
21	action authority under section 2371 of title 10,
22	United States Code, or another such arrangement.
23	(7) Reports.—
24	(A) Report by secretary of defense
25	AND DIRECTOR OF NATIONAL INTELLIGENCE.—

1	Not later than 90 days after the date of the en-
2	actment of this Act, the Secretary of Defense
3	and the Director of National Intelligence shall
4	jointly submit to Congress a report on the plans
5	of the Secretary and the Director to provide in-
6	centives under paragraph (1).
7	(B) BIENNIAL REPORTS BY COMPTROLLER
8	GENERAL OF THE UNITED STATES.—Not later
9	than 1 year after the date on which the Sec-
10	retary submits the report required by subpara-
11	graph (A) and not less frequently than once
12	every 2 years thereafter, the Comptroller Gen-
13	eral of the United States shall submit to Con-
14	gress a report on the activities carried out
15	under this subsection.
16	(8) Authorization of appropriations.—
17	There is authorized to be appropriated to carry out
18	this subsection $\$5,000,000,000$ for fiscal year 2021,
19	with such amount to remain available for such pur-
20	pose until September 30, 2031.
21	(c) Additional Amounts for Ensuring the Fu-
22	TURE OF UNITED STATES LEADERSHIP IN MICROELEC-
23	TRONICS.—
24	(1) Authorization of appropriations.—
25	There is authorized to be appropriated

\$2,000,000,000 for fiscal year 2021, with such amount to remain available until September 30, 2031, to expand the Electronics Resurgence Initia-tive of the Defense Advanced Research Projects Agency to develop advanced disruptive microelec-tronics technology, including research and develop-ment to enable production at a volume required to sustain a robust domestic microelectronics industry and mitigate parts obsolescence.

- (2) AUTHORIZATION OF APPROPRIATIONS.—
 There is authorized to be appropriated to carry out microelectronics research at the National Science Foundation \$1,500,000,000 for fiscal year 2021, with such amount to remain available for such purpose until September 30, 2031.
- (3) AUTHORIZATION OF APPROPRIATIONS.—
 There is authorized to be appropriated to carry out microelectronics research at the Department of Energy \$1,250,000,000 for fiscal year 2021, with such amount to remain available for such purpose until September 30, 2031.
- (4) Authorization of appropriations.—
 There is authorized to be appropriated to carry out microelectronics research at the National Institute of Standards and Technology \$250,000,000 for fiscal

year 2021, with such amount to remain available for such purpose until September 30, 2031.

- (5) SUPPLEMENT, NOT SUPPLANT.—The amounts authorized to be appropriated under paragraphs (1) through (4) shall supplement and not supplant amounts already appropriated to carry out the purposes described in such paragraphs.
- (6) Domestic production requirements.—
 The heads of executive agencies receiving funding under this section shall develop policies to require domestic production, to the extent possible, for any intellectual property resulting from microelectronics research and development conducted as a result of these funds and domestic control requirements to protect any such intellectual property from foreign adversaries.
- (7) Sense of congress.—Congress supports and encourages efforts by the heads of executive agencies receiving funding under this subsection to co-invest in industry-led microelectronics investment consortiums to increase private capital investment in the domestic microelectronics industry.
- 23 (d) National Microelectronics Research and
- 24 Development Plan.—

1	(1) In general.—The President shall establish
2	a standing subcommittee of the President's Office of
3	Science and Technology's National Science and
4	Technology Council for interagency efforts relating
5	to microelectronics policy.
6	(2) National microelectronics research
7	PLAN.—
8	(A) In general.—The subcommittee es-
9	tablished under paragraph (1) shall develop a
10	national microelectronics research and develop-
11	ment plan to guide and coordinate funding for
12	breakthroughs in next-generation microelec-
13	tronics research and technology, strengthen the
14	domestic microelectronics workforce, and en-
15	courage collaboration between government, in-
16	dustry, and academia.
17	(B) UPDATES.—Not less frequently than
18	once each year, the subcommittee established
19	under paragraph (1) shall update the plan de-
20	veloped under subparagraph (A) of this para-
21	graph.
22	(e) Industry Advisory Committee.—The Presi-
23	dent shall establish a standing subcommittee of the Presi-
24	dent's Council of Advisors on Science and Technology to

1	advise the United States Government on matters relating
2	to microelectronics policy.
3	(f) Multilateral Export Control Plan.—Not
4	later than 180 days after the date of the enactment of
5	this Act, the Secretary of State, the Secretary of the
6	Treasury, and the Secretary of Commerce, in consultation
7	with the Director of National Intelligence, the Secretary
8	of Homeland Security, the Secretary of Defense, and the
9	Secretary of Energy, shall jointly develop and submit to
10	Congress a plan to coordinate with foreign government
11	partners on establishing common microelectronics export
12	control and foreign direct investment screening measures
13	to align with national and multilateral security priorities.
14	(g) Prohibition Relating to Foreign Adver-
15	SARIES.—None of the funds appropriated pursuant to an
16	authorization in this section may be provided to an enti-

(1) under the foreign ownership, control, or influence of the Government of the People's Republic
of China or the Chinese Communist Party, or other
foreign adversary; or

(2) determined to have beneficial ownership from foreign individuals subject to the jurisdiction, direction, or influence of foreign adversaries.

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1	(h) Requirements for Sourcing From Domestic
2	MICROELECTRONICS DESIGN AND FOUNDRY SERVICES.—
3	(1) REQUIREMENTS REQUIRED.—Not later
4	than 1 year after the date of the enactment of this
5	Act, the Secretary of Defense shall establish require
6	ments, and a timeline for enforcement of such re-
7	quirements, to the extent possible, for domestic
8	sourcing for microelectronics design and foundry
9	services by programs, contractors, subcontractors
10	and other recipients of funding from the Departmen
11	of Defense.
12	(2) Processes for waivers.—The require
13	ments established under paragraph (1) shall include
14	processes to permit waivers for specific contracts or
15	transactions for domestic sourcing requirements
16	based on cost, availability, severity of technical and
17	mission requirements, emergency requirements and
18	operational needs, other legal or international treaty
19	obligations, or other factors.
20	(3) UPDATES.—Not less frequently than once
21	each year, the Secretary shall—
22	(A) update the requirements and timelines
23	established under paragraph (1) and the proc
24	esses under paragraph (2); and

1	(B) submit to Congress a report on the up-
2	dates made under subparagraph (A).
3	(i) Definitions.—In this section:
4	(1) Beneficial owner; beneficial owner-
5	SHIP.—The terms "beneficial owner" and "beneficial
6	ownership" have the meanings given such terms in
7	section 847 of the National Defense Authorization
8	Act for Fiscal Year 2020 (Public Law 116–92).
9	(2) Entity; company.—The terms "entity"
10	and "company" mean any corporation, company,
11	limited liability company, limited partnership, busi-
12	ness trust, business association, or other similar en-
13	tity.
14	(3) Foreign ownership, control, or influ-
15	ENCE.—The term "foreign ownership, control, or in-
16	fluence" has the meaning given such term in section
17	847 of the National Defense Authorization Act for
18	Fiscal Year 2020 (Public Law 116–92).
19	(4) Intelligence community.—In this sec-
20	tion, the term "intelligence community" has the
21	meaning given such term in section 3 of the Na-
22	tional Security Act of 1947 (50 U.S.C. 3003).